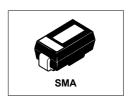
International Rectifier

MBRA120

SCHOTTKY RECTIFIER

1.0 Amp



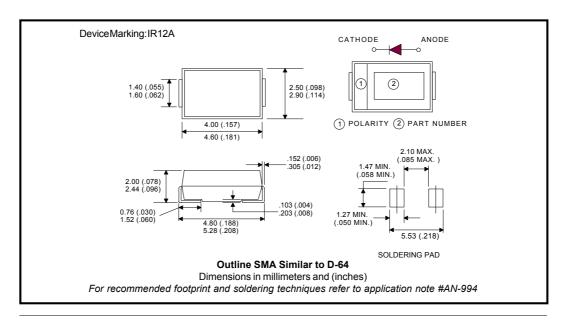
Major Ratings and Characteristics

Cha	racteristics	MBRA120	Units
I _{FAV}	Rect. Waveform	1.0	А
V _{RRM}		20	V
I _{FSM}	@tp=5 µs sine	310	Α
V _F	@1.0Apk,T _J =125°C	0.34	V
T _J	range	- 65 to 150	°C

Description/Features

The MBRA120 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Bulletin PD-20643 rev. B 03/02



Voltage Ratings

Part number	MBRA120	
V _R Max. DC Reverse Voltage (V)	20	
V _{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters		Value	Units	Conditions		
I _{F(AV)} Max. Average Forward Current		1.0	Α	50%duty cycle@T _L =136°C,rectangular waveform		
I _{FSM}	Max.PeakOneCycleNon-Repetitive	310		5μs Sine or 3μs Rect. pulse	Following any rated load condition and	
	SurgeCurrent	40		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied	
E _{AS}	Non Repetitive Avalanche Energy	3	mJ	T _J =25°C,I _{AS} =1A,L=10mH		
I _{AR}	Repetitive Avalanche Current	0.8	Α			

Electrical Specifications

	Parameters	Тур.	Max.	Units	Conditio	าร
V _{FM}	Max. Forward Voltage Drop (1)	0.42	0.45	٧	@ 1A	T - 25 °C
		0.46	0.52	V	@ 2A	T _J = 25 °C
		0.33	0.37	V	@ 1A	T = 400 °C
		0.39	0.45	V	@ 2A	T _J = 100 °C
		0.30	0.35	V	@ 1A	T,= 125 °C
		0.36	0.43	٧	@ 2A	1 _J - 125 C
I _{RM}	Max.ReverseLeakageCurrent (1)	0.015	0.2	mA	T _J = 25 °C	
		2.0	6.0	mA	T _J = 100 °C	V _R = rated V _R
		7.0	20	mA	T _J = 125 °C	
C _T	C _T Typical Junction Capacitance		-	pF	$V_R = 5V_{DC}$ (test signal range 100kHz to	
					1Mhz), @ 25	°C
L _S	L _S Typical Series Inductance		-	nΗ	Measured lead to lead 5mm from package body	
dv/dt	dv/dt Max. Voltage Rate of Change		10000	V/ µs	(Rated V _R)	

⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters		Units	Conditions
T _J	Max.JunctionTemperatureRange (*)	-65 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-65 to 150	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead (**)	35	°C/W	DCoperation
R _{thJA}	Max.ThermalResistanceJunction	80	°C/W	
	toAmbient			
Wt	Approximate Weight	0.07(0.002)	gr(oz)	
	Case Style		١	SimilarD-64
	Device Marking IR12A		4	

 $[\]frac{\text{(*)}}{\text{dTj}} < \frac{\text{1}}{\text{Rth(j-a)}} \text{ thermal runaway condition for a diode on its own heatsink}$

^(**) Mounted 1 inch square PCB

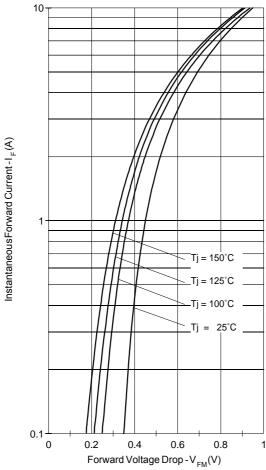


Fig. 1-Maximum Forward Voltage Drop Characteristics

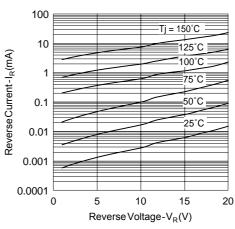


Fig.2-Typical Peak Reverse Current Vs. Reverse Voltage

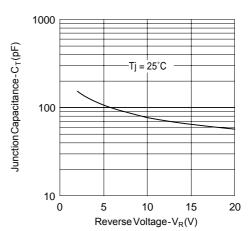


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

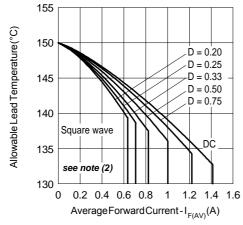


Fig. 4-Maximum Average Forward Current Vs. Allowable Lead Temperature

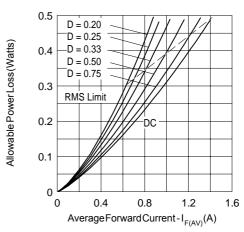


Fig. 5-Maximum Average Forward Dissipation Vs. Average Forward Current

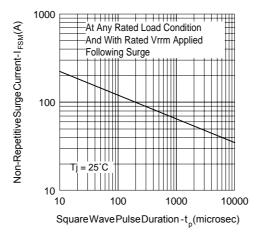
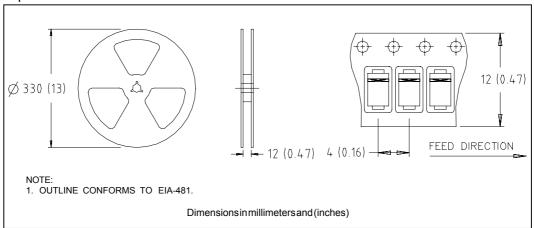


Fig. 6-Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6); $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1 - D)$

Tape & Reel Information



Marking & Identification

Ordering Information

 $Each \, device \, has \, marking \, and \, identification \, on \, two \, rows.$

- The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", then Current, Voltage.
- -The second row shows the data code: Year and Week.

See below marking diagram.

FIRST ROW

IR12A

SECOND ROW

Date Code YY WW

MBRA120TR - TAPE AND REEL

WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 7500 PIECES).

EXAMPLE: MBRA120TR - 15000 PIECES

Data and specifications subject to change without notice.

This product has been designed for Industrial Level.

Qualification Standards can be found on IR's Web site.



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TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/02